NSN 5961-00-104-8612

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View Online at https://aerobasegroup.com/nsn/5961-00-104-8612 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.335 inches **End Application:** Communications and data systems. B-52 stratofortress, s-3b viking aircraft **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open all transistor and 60.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 150.0 small-signal short-circuit forward current transfer ratio, common-emitter all transistor **Special Features:** Weapon system essential. Features - all transistor junction pattern arrangement: pnp. **Terminal Type And Quantity:** 7 uninsulated wire lead **Specification Data:** 80131-release5128 professional/industrial association specification Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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